

<b>L Number</b>	<b>Hits</b>	<b>Search Text</b>	<b>DB</b>	<b>Tim stamp</b>
<b>1</b>	<b>627</b>	<b>display and semiconductor and (i n adj implant\$) and lectr de and drain and gat and method and capacit r</b>	<b>US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USOCR</b>	<b>2004/05/17 06:02</b>
<b>2</b>	<b>0</b>	<b>display and semiconductor and (ion adj implant\$) and electrode and drain and gate and method and capacitor</b>		<b>2004/05/17 06:02</b>
<b>3</b>	<b>3</b>	<b>display and semiconductor and (ion adj implant\$) and electrode and drain and gate and method and capacitor</b>	<b>EPO; JPO; DERWENT; IBM_TDB</b>	<b>2004/05/17 06:02</b>
<b>4</b>	<b>624</b>	<b>display and semiconductor and (ion adj implant\$) and electrode and drain and gate and method and capacitor</b>	<b>US-PGPUB</b>	<b>2004/05/17 06:02</b>